Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

Send any inquiries to http://www.renesas.com/inquiry.



Notice

- 1. All information included in this document is current as of the date this document is issued. Such information, however, is subject to change without any prior notice. Before purchasing or using any Renesas Electronics products listed herein, please confirm the latest product information with a Renesas Electronics sales office. Also, please pay regular and careful attention to additional and different information to be disclosed by Renesas Electronics such as that disclosed through our website.
- Renesas Electronics does not assume any liability for infringement of patents, copyrights, or other intellectual property rights
 of third parties by or arising from the use of Renesas Electronics products or technical information described in this document.
 No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights
 of Renesas Electronics or others.
- 3. You should not alter, modify, copy, or otherwise misappropriate any Renesas Electronics product, whether in whole or in part.
- 4. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation of these circuits, software, and information in the design of your equipment. Renesas Electronics assumes no responsibility for any losses incurred by you or third parties arising from the use of these circuits, software, or information.
- 5. When exporting the products or technology described in this document, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations. You should not use Renesas Electronics products or the technology described in this document for any purpose relating to military applications or use by the military, including but not limited to the development of weapons of mass destruction. Renesas Electronics products and technology may not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations.
- 6. Renesas Electronics has used reasonable care in preparing the information included in this document, but Renesas Electronics does not warrant that such information is error free. Renesas Electronics assumes no liability whatsoever for any damages incurred by you resulting from errors in or omissions from the information included herein.
- 7. Renesas Electronics products are classified according to the following three quality grades: "Standard", "High Quality", and "Specific". The recommended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below. You must check the quality grade of each Renesas Electronics product before using it in a particular application. You may not use any Renesas Electronics product for any application categorized as "Specific" without the prior written consent of Renesas Electronics. Further, you may not use any Renesas Electronics product for any application for which it is not intended without the prior written consent of Renesas Electronics. Renesas Electronics shall not be in any way liable for any damages or losses incurred by you or third parties arising from the use of any Renesas Electronics product for an application categorized as "Specific" or for which the product is not intended where you have failed to obtain the prior written consent of Renesas Electronics. The quality grade of each Renesas Electronics product is "Standard" unless otherwise expressly specified in a Renesas Electronics data sheets or data books, etc.
 - "Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; and industrial robots.
 - "High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control systems; anti-disaster systems; anti-crime systems; safety equipment; and medical equipment not specifically designed for life support.
 - "Specific": Aircraft; aerospace equipment; submersible repeaters; nuclear reactor control systems; medical equipment or systems for life support (e.g. artificial life support devices or systems), surgical implantations, or healthcare intervention (e.g. excision, etc.), and any other applications or purposes that pose a direct threat to human life.
- 8. You should use the Renesas Electronics products described in this document within the range specified by Renesas Electronics, especially with respect to the maximum rating, operating supply voltage range, movement power voltage range, heat radiation characteristics, installation and other product characteristics. Renesas Electronics shall have no liability for malfunctions or damages arising out of the use of Renesas Electronics products beyond such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of its products, semiconductor products have specific characteristics such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Further, Renesas Electronics products are not subject to radiation resistance design. Please be sure to implement safety measures to guard them against the possibility of physical injury, and injury or damage caused by fire in the event of the failure of a Renesas Electronics product, such as safety design for hardware and software including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult, please evaluate the safety of the final products or system manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. Please use Renesas Electronics products in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. Renesas Electronics assumes no liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. This document may not be reproduced or duplicated, in any form, in whole or in part, without prior written consent of Renesas Electronics
- 12. Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products, or if you have any other inquiries.
- (Note 1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its majority-owned subsidiaries.
- (Note 2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.





PHOTOCOUPLER

PS9552,PS9552L1,PS9552L2,PS9552L3

2.5 A OUTPUT CURRENT. HIGH CMR IGBT GATE DRIVE PHOTOCOUPLER 8-PIN DIP PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS9552, PS9552L1, PS9552L2 and PS9552L3 are optically coupled isolators containing a GaAlAs LED on the input side and a photo diode, a signal processing circuit and a power output transistor on the output side on one chip.

The PS9552 Series is designed specifically for high common mode transient immunity (CMR), high output current and high switching speed.

The PS9552 Series is suitable for driving IGBTs and MOS FETs.

The PS9552 Series is in a plastic DIP (Dual In-line Package).

The PS9552L1 is lead bending type for long creepage distance.

The PS9552L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

The PS9552L3 is lead bending type (Gull-wing) for surface mounting.

FEATURES

- Long creepage distance (8 mm MIN.: PS9552L1, PS9552L2)
- Large peak output current (2.5 A MAX., 2.0 A MIN.)
- High speed switching (tplh, tphl = $0.5 \mu s$ MAX.)
- · UVLO (Under Voltage Lock Out) protection with hysteresis
- High common mode transient immunity (CMH, CML = $\pm 25 \text{ kV/}\mu\text{s MIN.}$)
- Ordering number of tape product: PS9552L2-E3: 1 000 pcs/reel

: PS9552L3-E3: 1 000 pcs/reel

<R>

- Pb-Free product
- Safety standards
 - UL approved: No. E72422

 CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950) <R>

> BSI approved: No. 8937, 8938 SEMKO approved: No. 615433

NEMKO approved: No. P06207243

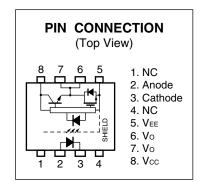
• DEMKO approved: No. 314091

FIMKO approved: No. FI 22827

<R> DIN EN60747-5-2 (VDE0884 Part2) approved: No. 40019182 (Option)

APPLICATIONS

- IGBT, Power MOS FET Gate Driver
- Industrial inverter
- IH (Induction Heating)

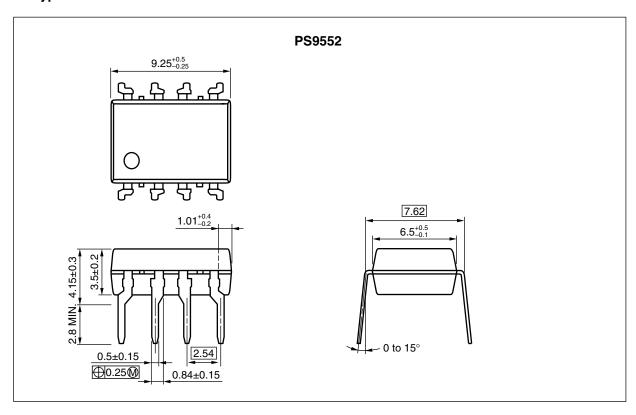


The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

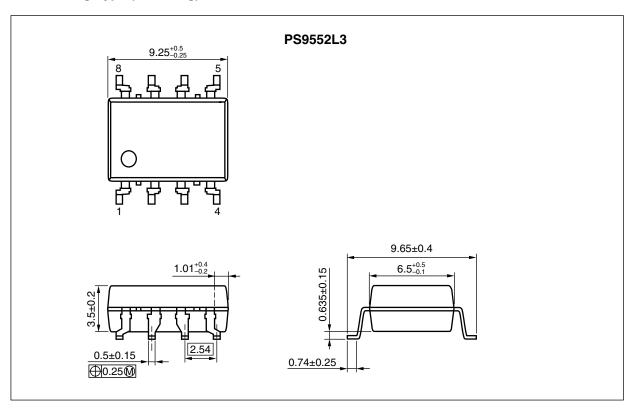
Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

<R> PACKAGE DIMENSIONS (UNIT: mm)

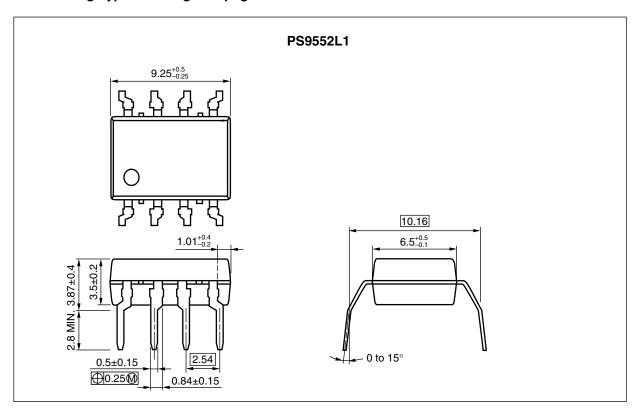
DIP Type



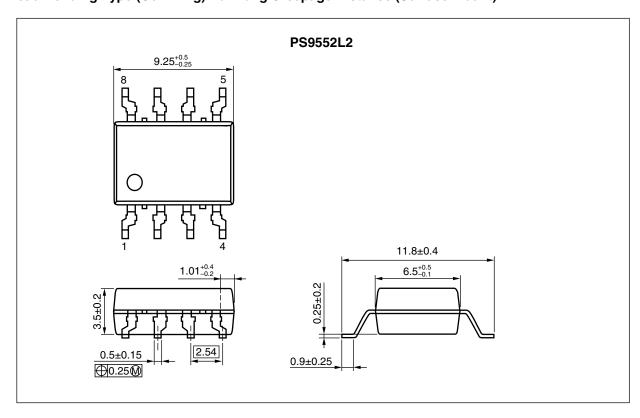
Lead Bending Type (Gull-wing) For Surface Mount



Lead Bending Type For Long Creepage Distance



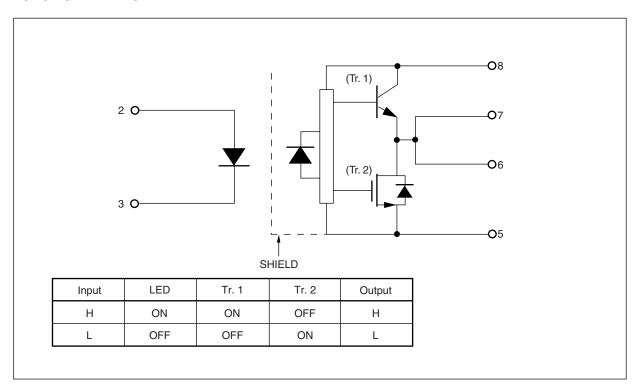
Lead Bending Type (Gull-wing) For Long Creepage Distance (Surface Mount)



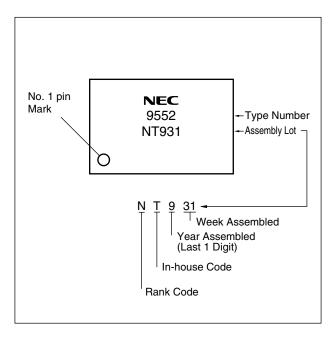
PHOTOCOUPLER CONSTRUCTION

Parameter	PS9552, PS9552L3	PS9552L1, PS9552L2
Air Distance (MIN.)	7 mm	8 mm
Outer Creepage Distance (MIN.)	7 mm	8 mm
Isolation Distance (MIN.)	0.4 mm	0.4 mm

FUNCTIONAL DIAGRAM



<R> MARKING EXAMPLE



ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number* ¹
PS9552	PS9552-AX	Pb-Free	Magazine case 50 pcs	Standard products	PS9552
PS9552L1	PS9552L1-AX	(Ni/Pd/Au)		(UL, CSA, BSI,	PS9552L1
PS9552L2	PS9552L2-AX			SEMKO, NEMKO,	PS9552L2
PS9552L3	PS9552L3-AX			DEMKO, FIMKO	PS9552L3
PS9552L2-E3	PS9552L2-E3-AX		Embossed Tape 1 000 pcs/reel	approved)	PS9552L2
PS9552L3-E3	PS9552L3-E3-AX				PS9552L3
PS9552-V	PS9552-V-AX		Magazine case 50 pcs	DIN EN60747-5-2	PS9552
PS9552L1-V	PS9552L1-V-AX			(VDE0884 Part2)	PS9552L1
PS9552L2-V	PS9552L2-V-AX			Approved (Option)	PS9552L2
PS9552L3-V	PS9552L3-V-AX				PS9552L3
PS9552L2-V-E3	PS9552L2-V-E3-AX		Embossed Tape 1 000 pcs/reel		PS9552L2
PS9552L3-V-E3	PS9552L3-V-E3-AX				PS9552L3

^{*1} For the application of the Safety Standard, following part number should be used.



ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current	lF	25	mA
	Peak Transient Forward Current (Pulse Width < 1 μ s)	IF (TRAN)	1.0	Α
	Reverse Voltage	VR	5	V
Detector	High Level Peak Output Current	Іон (реак)	2.5	Α
	Low Level Peak Output Current	OL (PEAK)	2.5	Α
	Supply Voltage	(Vcc - Vee)	0 to 35	V
	Output Voltage	Vo	0 to Vcc	V
	Power Dissipation '2	Pc	250	mW
Isolation	Voltage ^{*3}	BV	5 000	Vr.m.s.
Total Power Dissipation *4		Рт	300	mW
Operating Frequency '5		f	50	kHz
Operating Ambient Temperature		TA	-40 to +100	°C
Storage Temperature		T _{stg}	-55 to +125	°C

^{*1} Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	(Vcc - Vee)	15		30	٧
Forward Current (ON)	IF (ON)	7	10	16	mA
Forward Voltage (OFF)	V _F (OFF)	-2		0.8	٧
Operating Ambient Temperature	Та	-40		100	°C

^{*2} Reduced to 4.8 mW/ $^{\circ}$ C at T_A = 70 $^{\circ}$ C or more.

^{*3} AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.

^{*4} Reduced to 5.4 mW/ $^{\circ}$ C at T_A = 70 $^{\circ}$ C or more.

^{*5} IOH (PEAK) \leq 2.0 A (\leq 0.3 μ s), IOL (PEAK) \leq 2.0 A (\leq 0.3 μ s)

ELECTRICAL CHARACTERISTICS (Ta = -40 to +100°C, Vcc = 15 to 30 V, I_F (ON) = 7 to 16 mA, V_F (OFF) = -2 to 0.8 V, VEE = GND, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP. ^{*1}	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA, T _A = 25°C	1.3	1.65	2.1	V
	Input Capacitance	Cin	f = 1 MHz, V _F = 0 V, T _A = 25°C		30		pF
Detector	High Level Output Current	Іон	Vo = (Vcc - 4 V) 2	0.5	2.0		Α
			Vo = (Vcc - 15 V)*3	2.0			
	Low Level Output Current	loL	Vo = (VEE + 2.5 V) *2	0.5	2.0		Α
			Vo = (VEE + 15 V) *3	2.0			
	High Level Output Voltage	Vон	lo = −100 mA ^{*4}	Vcc - 3.5	Vcc - 2.5	Vcc - 1.5	V
	Low Level Output Voltage	Vol	lo = 100 mA		0.1	0.5	V
	High Level Supply Current	Іссн	Vo = open, I _F = 7 to 16 mA		2.0	5.0	mA
	Low Level Supply Current	Iccl	Vo = open, V _F = -2 to +0.8 V		2.0	5.0	mA
	UVLO Threshold	Vuvlo+	Vo > 5 V, IF = 10 mA	11.0	12.3	13.5	V
		V UVLO-		9.5	10.7	12.0	
	UVLO Hysteresis	UVLO _{HYS}	Vo > 5 V, IF = 10 mA		1.6		V
Coupled	Threshold Input Current $(L \rightarrow H)$	lflh	lo = 0 mA, Vo > 5 V		2.0	5.0	mA
	Threshold Input Voltage $(H \rightarrow L)$	V _{FHL}	Io = 0 mA, Vo < 5 V	0.8			V

^{*1} Typical values at $T_A = 25^{\circ}C$.

<R>

^{*2} Maximum pulse width = 50 μ s, Maximum duty cycle = 0.5%.

^{*3} Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%

^{*4} VoH is measured with the DC load current in this testing (Maximum pulse width = 2 ms, Maximum duty cycle = 20%).



SWITCHING CHARACTERISTICS (Ta = -40 to +100°C, Vcc = 15 to 30 V, IF (ON) = 7 to 16 mA, VF (OFF) = -2 to 0.8 V, VEE = GND, unless otherwise specified)

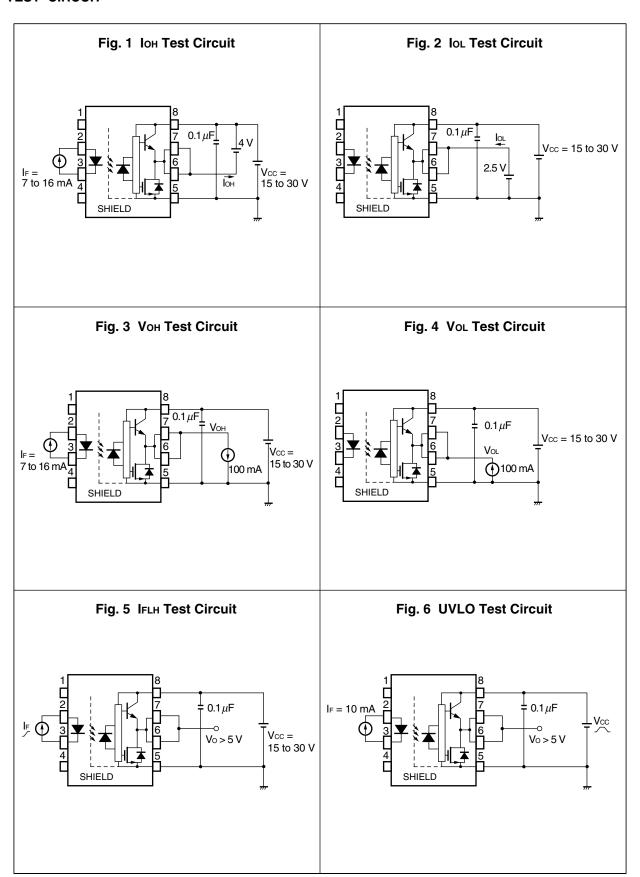
Parameter	Symbol	Conditions	MIN.	TYP. ^{*1}	MAX.	Unit
Propagation Delay Time $(L \rightarrow H)$	t PLH	$R_g = 10 \ \Omega, \ C_g = 10 \ nF, \ f = 10 \ kHz,$	0.1	0.3	0.5	μs
Propagation Delay Time $(H \rightarrow L)$	t PHL	Duty Cycle = 50% ² , I _F = 7 to 16 mA	0.1	0.3	0.5	μs
Pulse Width Distortion (PWD)	tрнц—tрцн				0.3	μs
Propagation Delay Time (Difference Between Any Two Products)	tрнц—tрцн		-0.35		0.35	μs
Rise Time	tr			0.1		μs
Fall Time	tr			0.1		μs
UVLO (Turn On Delay)	tuvlo on	Vo > 5 V, IF = 10 mA		0.8		μs
UVLO (Turn Off Delay)	tuvlo off	Vo < 5 V, I _F = 10 mA		0.6		μs
Common Mode Transient Immunity at High Level Output ³	[СМн]	$T_{A} = 25^{\circ}C, \ I_{F} = 10 \ to \ 16 \ mA, \ V_{CC} = 30 \ V, \\ V_{O \ (MIN.)} = 26 \ V, \ V_{CM} = 1.5k \ V$	25			kV/μs
Common Mode Transient Immunity at Low Level Output ³	CML	T _A = 25°C, I _F = 0 mA, V _{CC} = 30 V, V _{O (MAX.)} = 1 V, V _{CM} = 1.5k V	25			kV/μs

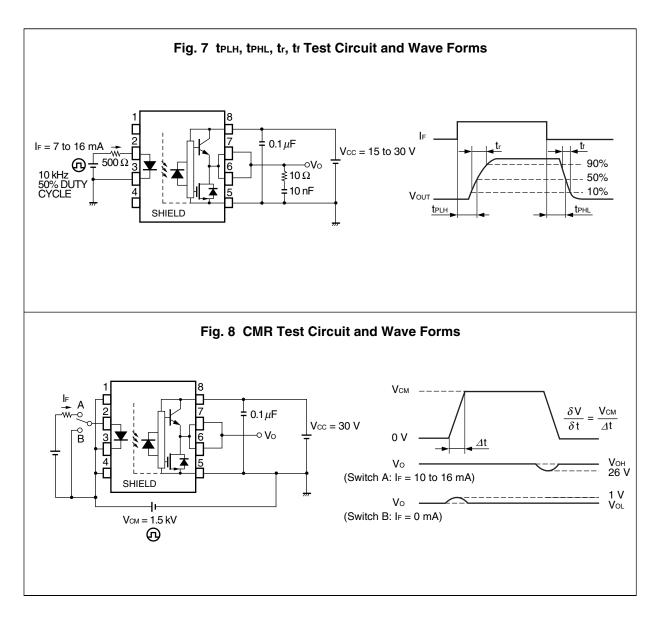
^{*1} Typical values at $T_A = 25^{\circ}C$.

^{*2} This load condition is equivalent to the IGBT load at 1 200 V/75 A.

^{*3} Connect pin 1 and pin 4 to the LED common.

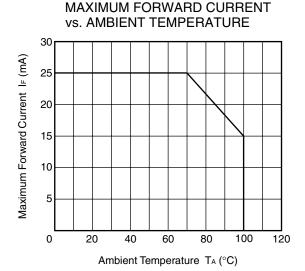
TEST CIRCUIT

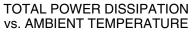


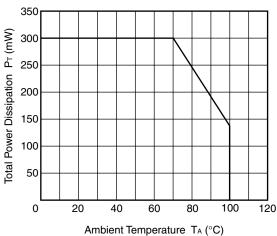


Remark CMR Test: Connect pin 1 and pin 4 to the LED common.

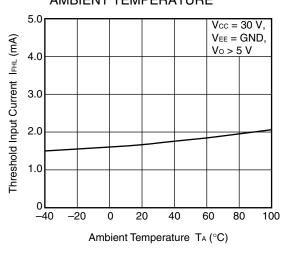
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



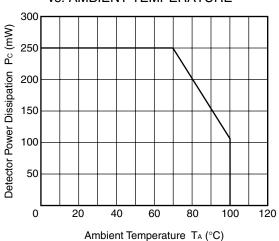




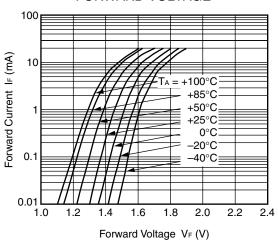
THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



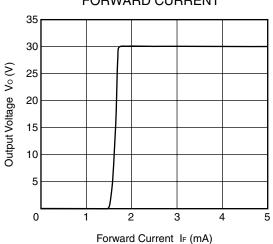
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



FORWARD CURRENT vs. FORWARD VOLTAGE

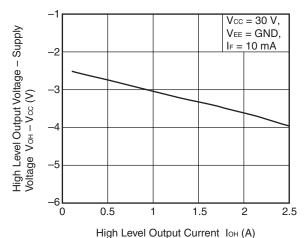


OUTPUT VOLTAGE vs. FORWARD CURRENT

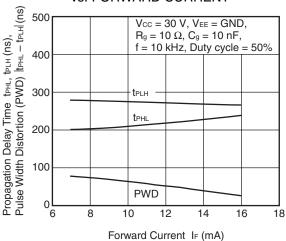


Remark The graphs indicate nominal characteristics.

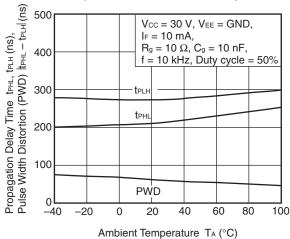
<R> HIGH LEVEL OUTPUT VOLTAGE – SUPPLY VOLTAGE vs. HIGH LEVEL OUTPUT CURRENT



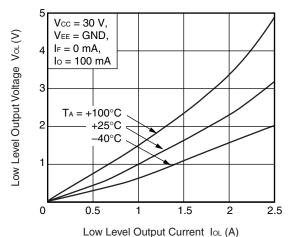
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. FORWARD CURRENT



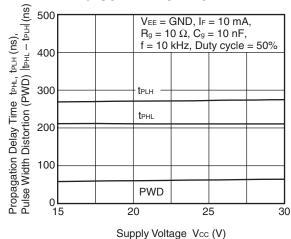
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. AMBIENT TEMPERATURE



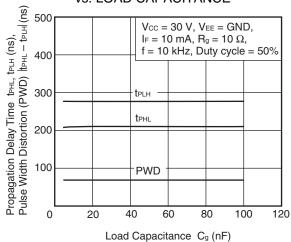
LOW LEVEL OUTPUT VOLTAGE vs. LOW LEVEL OUTPUT CURRENT



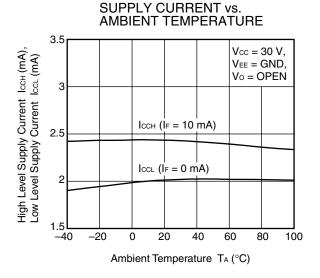
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. SUPPLY VOLTAGE



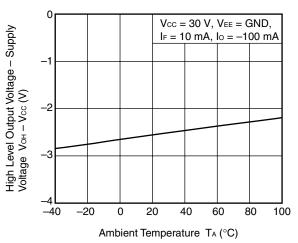
PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. LOAD CAPACITANCE



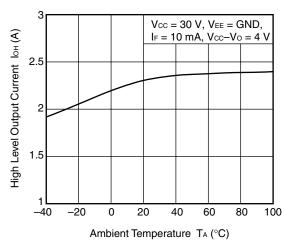
Remark The graphs indicate nominal characteristics.



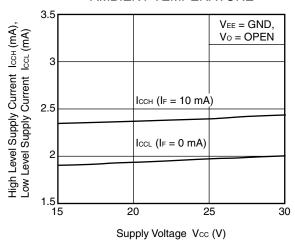
HIGH LEVEL OUTPUT VOLTAGE – SUPPLY VOLTAGE vs. AMBIENT TEMPERATURE



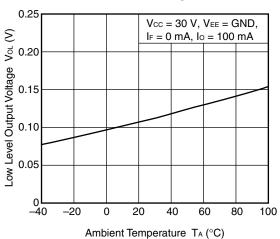
HIGH LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



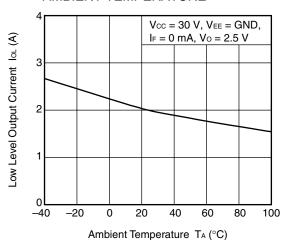
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE

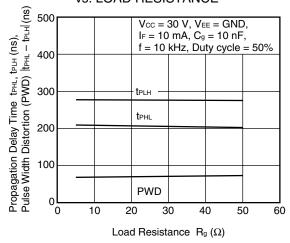


LOW LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



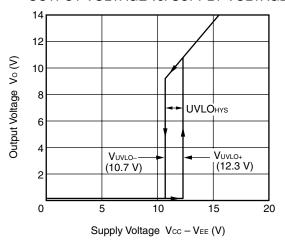
Remark The graphs indicate nominal characteristics.

PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. LOAD RESISTANCE

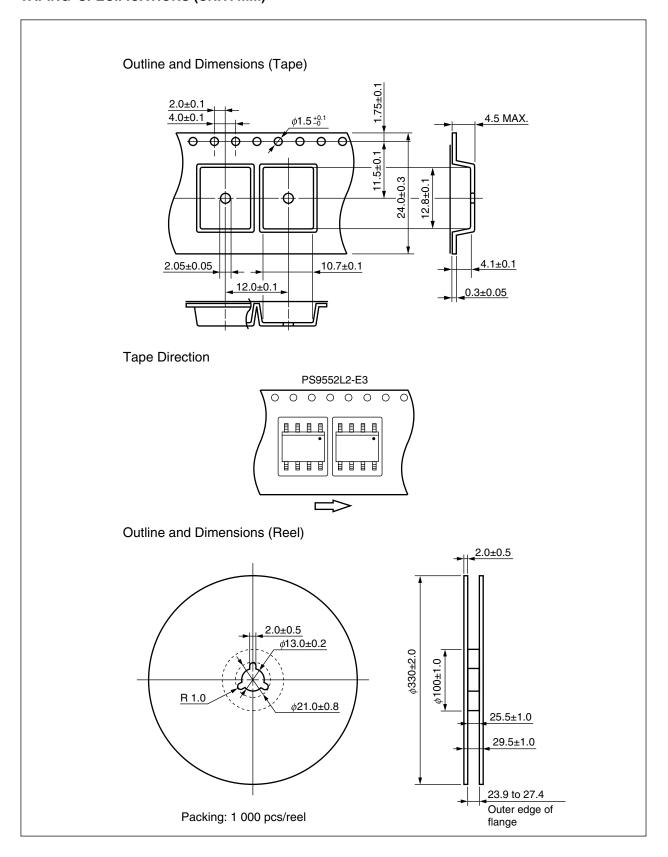


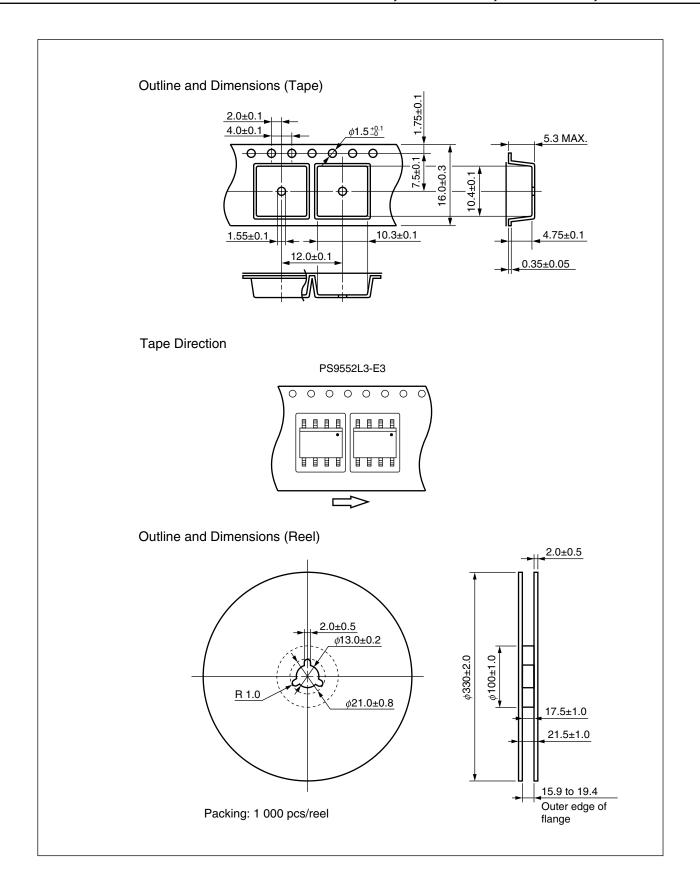
Remark The graphs indicate nominal characteristics.

OUTPUT VOLTAGE vs. SUPPLY VOLTAGE

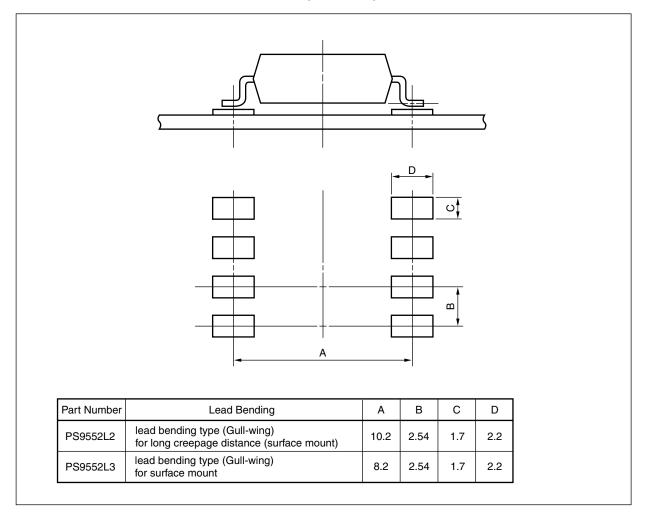


TAPING SPECIFICATIONS (UNIT: mm)





RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

Peak reflow temperature
 260°C or below (package surface temperature)

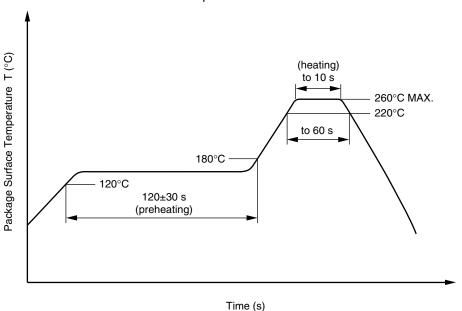
Time of peak reflow temperature
 Time of temperature higher than 220°C
 10 seconds or less
 60 seconds or less

Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

Flux
 Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

Number of times
 One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature) 350°C or below
 Time (each pins) 3 seconds or less

Flux
 Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. Board designing
 - (1) By-pass capacitor of more than 0.1 μ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
 - (2) In older to avoid malfunctions and characteristics degradation, IGBT collector or emitter traces should not be closed to the LED input.
 - (3) Pins 1, 4 (which is an NC^{*1} pin) can either be connected directly to the GND pin on the LED side or left open. Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.
 - *1 NC: Non-Connection (No Connection)
- 3. Make sure the rise/fall time of the forward current is 0.5 μ s or less.
- **4.** In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is $3 \text{ V}/\mu\text{s}$ or less.
- 5. Avoid storage at a high temperature and high humidity.

<R>



<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	1 130	V_{peak}
Test voltage (partial discharge test, procedure a for type test and random test)	U_pr	1 695	V_{peak}
$U_{pr} = 1.5 \times U_{IORM}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_pr	2 119	V_{peak}
$U_{pr} = 1.875 \times U_{IORM}, P_d < 5 pC$			
Highest permissible overvoltage	Utr	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T _{stg}	-55 to +125	°C
Operating temperature range	TA	-40 to +100	°C
Isolation resistance, minimum value			
V _{IO} = 500 V dc at T _A = 25°C	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current IF, Psi = 0)	Isi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
$V_{IO} = 500 \text{ V dc at } T_A = T_{SI}$	Ris MIN.	10°	Ω

- The information in this document is current as of September, 2009. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC Electronics data sheets, etc., for the most up-to-date specifications of NEC Electronics products. Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without the prior
 written consent of NEC Electronics. NEC Electronics assumes no responsibility for any errors that may
 appear in this document.
- NEC Electronics does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from the use of NEC Electronics products listed in this document or any other liability arising from the use of such products. No license, express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Electronics or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
 purposes in semiconductor product operation and application examples. The incorporation of these
 circuits, software and information in the design of a customer's equipment shall be done under the full
 responsibility of the customer. NEC Electronics assumes no responsibility for any losses incurred by
 customers or third parties arising from the use of these circuits, software and information.
- While NEC Electronics endeavors to enhance the quality and safety of NEC Electronics products, customers agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. In addition, NEC Electronics products are not taken measures to prevent radioactive rays in the product design. When customers use NEC Electronics products with their products, customers shall, on their own responsibility, incorporate sufficient safety measures such as redundancy, fire-containment and anti-failure features to their products in order to avoid risks of the damages to property (including public or social property) or injury (including death) to persons, as the result of defects of NEC Electronics products.
- NEC Electronics products are classified into the following three quality grades: "Standard", "Special" and "Specific".

The "Specific" quality grade applies only to NEC Electronics products developed based on a customerdesignated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).

M8E0904E

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.